

## **Features**

- · Advanced Trench MOSFET Process Technology
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

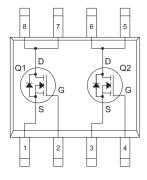
# **Maximum Ratings**

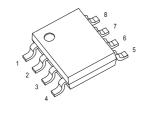
- \* Operating Junction Temperature Range: -55°C to +150°C
- \* Storage Temperature Range: -55°C to +150°C
- \* Thermal Resistance: 73.5°C/W Junction to Ambient(Note2)

Parameter	Symbol	Rating	Unit
Drain -Source Voltage	$V_{DS}$	60	V
Gate -Source Volltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	5	Α
Pulsed Drain Current(Note1)	I <sub>DM</sub>	30	Α
Power Dissipation	P <sub>D</sub>	1.7	W

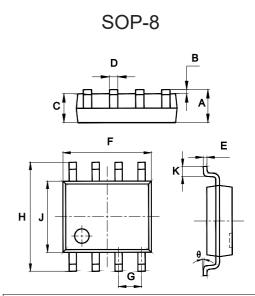
Noet:1.Repetitive Rating: Pulse width limited by maximum junction temperature. 2.Surface Mounted on FR4 Board, t ≤ 10 sec.

## **Internal Structure**



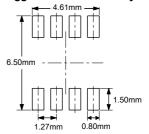


# **Dual N-Channel Power MOSFET**



DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	INOTE	
Α	0.053	0.069	1.35	1.75		
В	0.004	0.010	0.10	0.25		
С	0.053	0.061	1.35	1.55		
D	0.013	0.020	0.33	0.51		
E	0.007	0.010	0.17	0.25		
F	0.185	0.200	4.70	5.10		
G	0.050		1.270		TYP.	
Н	0.228	0.244	5.80	6.20		
J	0.150	0.157	3.80	4.00		
K	0.016	0.050	0.40	1.27		
θ	0°	8°	0°	8°		

#### Suggested Solder Pad Layout



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# **ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

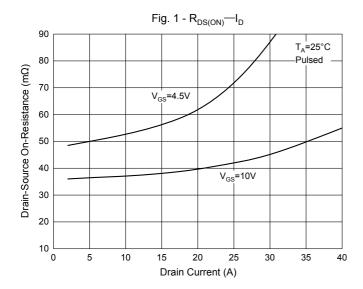
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Static Characteristics	1					
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	60			V
Gate-Threshold Voltage <sup>(Note3)</sup>	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	1.0		3.0	V
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =± 20V, V <sub>DS</sub> =0V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V			1	μA
Drain-Source On-Resistance(Note3)	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =5A		37	45	mΩ
Forward Transconductance <sup>(Note3)</sup>	g <sub>fs</sub>	V <sub>DS</sub> =5V, I <sub>D</sub> =4.5A	11			S
Dynamic Characteristics(Note4)						
Input Capacitance	C <sub>iss</sub>			500		
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =30V, $V_{GS}$ =0V, f=1MHz		60		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			25		
Switching Characteristics(Noted	1)					
Total Gate Charge	$Q_g$			12		nC
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =48V,V <sub>GS</sub> =10V,I <sub>D</sub> =15A		4.1		
Gate-Drain Charge	$Q_{gd}$			4.5		
Turn-on Delay Time	t <sub>d(on)</sub>			5.0		
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =30V, $V_{GS}$ =10V, $I_{D}$ =2A, $R_{G}$		2.6		
Turn-off Delay Time	t <sub>d(off)</sub>	=3 $\Omega$ , R <sub>L</sub> =6.7 $\Omega$		16.1		ns
Turn-off Fall Time	t <sub>f</sub>			2.3		
Drain-Source Diode Characteristics						
Diode Forward Voltage <sup>(Note3)</sup>	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>s</sub> =20A			1.2	V
Diode Forward Current <sup>(Note2)</sup>	I <sub>S</sub>				20	Α
Reverse Recovery Time	t <sub>rr</sub>			35		nS
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> =20A,di/dt=100A/us <sup>(Note4)</sup>		53		μC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)		)		

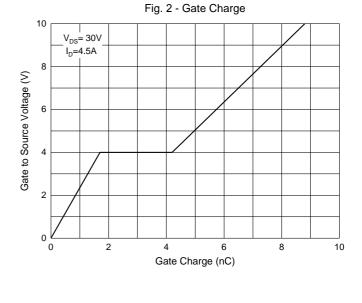
Note: 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.

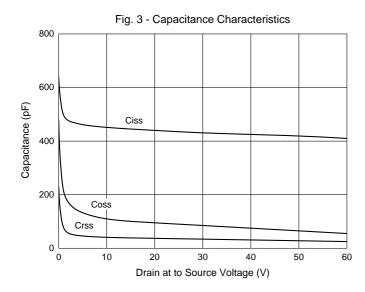
<sup>4.</sup> Guaranteed by design, not subject to production.

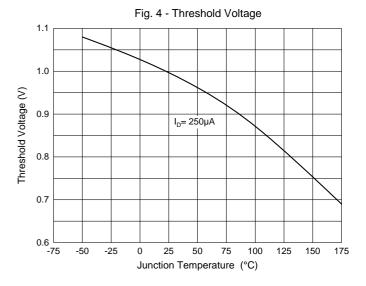


# **Curve Characteristics**











# **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel:4Kpcs/Reel

Note: Adding "-HF" Suffix For Halogen Free, eg. Part Number-TP-HF

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